

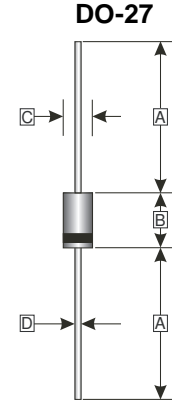
RoHS Compliant Product
A suffix of "-C" specifies halogen & lead-free

FEATURES

- Low forward voltage drop
- High current capability
- High reliability
- High surge current capability
- High speed switching

PACKAGING INFORMATION

- Case: Molded plastic
- Epoxy: UL 94V-0 rate flame retardant
- Lead: Axial leads, solderable per J-STD-002 and JESD22-B102
- Polarity: Color band denotes cathode end
- Mounting position: Any



REF.	Millimeter	
	Min.	Max.
A	25.4 (TYP)	
B	7.20	9.53
C	5.00	5.60
D	1.20	1.32

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS (T_A=25°C unless otherwise specified)

Parameter	Symbol	Rating	Unit
Repetitive Peak Reverse Voltage	V _{RRM}	600	V
Average Rectified Output Current@ 60Hz half-sine wave, resistance load, see fig. 1	I _O	4	A
Non-repetitive Surge Forward Current@ 60Hz half-sine wave, 1 cycle, T _A =25°C	I _{FSM}	100	A
Maximum Instantaneous Forward Voltage@ drop per diode, I _{FM} =4A	V _{FM}	1.25	V
Maximum DC Reverse Current at related DC Blocking Voltage@ per diode	I _R	T _A =25°C	10
		T _A =125°C	100
Typical Junction Capacitance ¹	C _J	65	pF
Reverse Recovery Time@ I _F =0.5A, I _R =1A, I _{RR} =0.25A	T _{RR}	50	nS
Typical Thermal Resistance from Junction to Ambient	R _{θJA}	25	°C /W
Typical Thermal Resistance from Junction to Lead	R _{θJL}	14	°C /W
Operating Junction and Storage Temperature Range	T _J , T _{STG}	150, -55 ~ 150	°C

Notes:

1. Measured at 1MHz and applied with 4.0V D.C reverse voltage.

CHARACTERISTIC CURVES

FIG.1: I_o - T_a Curve

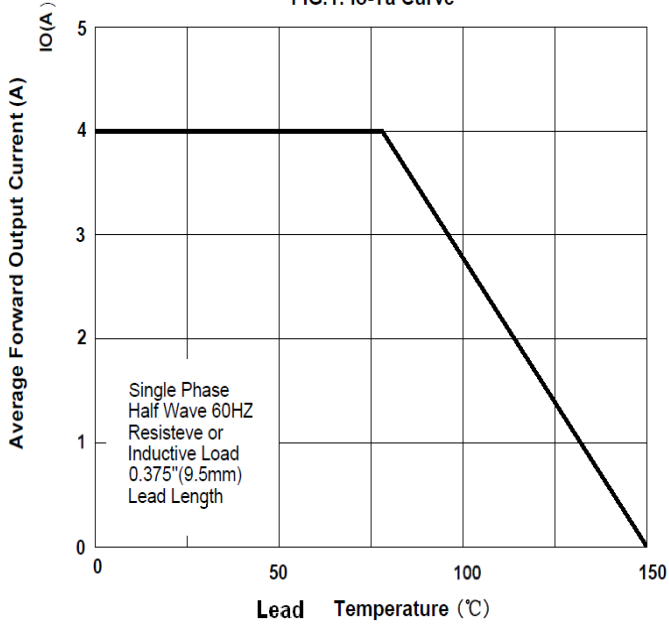


FIG.2: Surge Forward Current Capacity

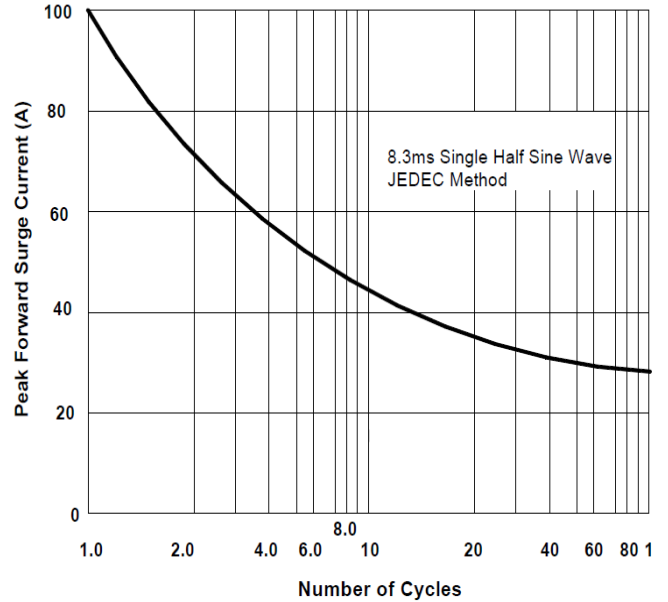


FIG.3: Forward Voltage

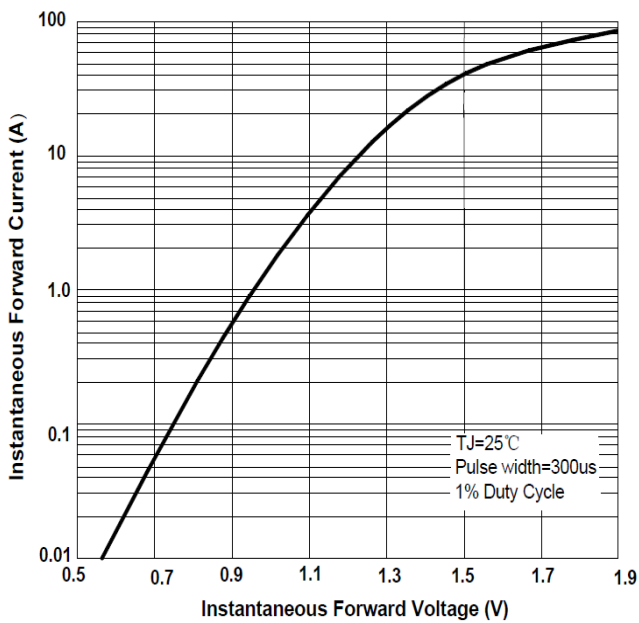


FIG.4: Typical Reverse Characteristics

